

2SC3281

SILICON NPN TRIPLE DIFFUSED TYPE

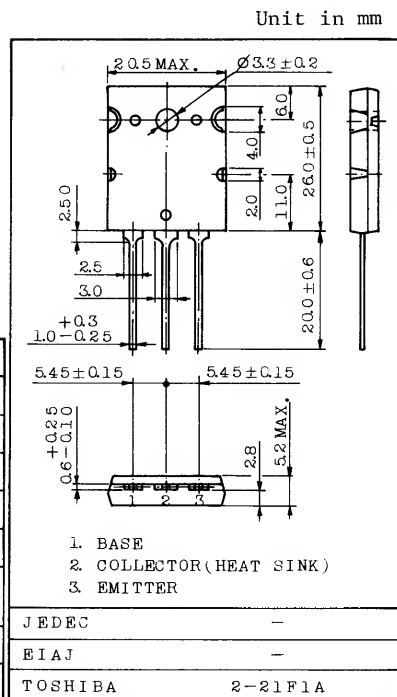
POWER AMPLIFIER APPLICATIONS.

FEATURES:

- Complementary to 2SA1302
- Recommend for 100W High Fidelity Audio Frequency Amplifier Output Stage.

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	200	V
Collector-Emitter Voltage	V _{CEO}	200	V
Emitter-Base Voltage	V _{EB0}	5	V
Collector Current	I _C	15	A
Base Current	I _B	1.5	A
Collector Power Dissipation (Tc=25°C)	P _C	150	W
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-55 ~ 150	°C



Weight : 9.75g

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I _{CBO}	V _{CB} =200V, I _E =0	-	-	5.0	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =5V, I _C =0	-	-	5.0	μA
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =50mA, I _B =0	200	-	-	V
DC Current Gain	h _{FE} (1) (Note)	V _{CE} =5V, I _C =1A	55	-	160	-
	h _{FE} (2)	V _{CE} =5V, I _C =8A	35	60	-	
Collector Emitter Saturation Voltage	V _{CE(sat)}	I _C =10A, I _B =1A	-	0.40	3.0	V
Base-Emitter Voltage	V _{BE}	V _{CE} =5V, I _C =8A	-	1.0	1.5	V
Transition Frequency	f _T	V _{CE} =5V, I _C =1A	-	30	-	MHz
Collector Output Capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz	-	270	-	pF

Note : h_{FE}(1) Classification R : 55~110, 0 : 80~160

